MicroBooNE Status



MicroBooNE (E-974)

- Liquid Argon Time Projection Chamber (LAr TPC)
 - o 170 tons LAr (~84t active)
 - Located on Booster Neutrino Beamline
- Major advance in neutrino detector technology
 - Purity without evacuation Initial demo by LAPD
 - Foam insulation
 - Cold electronics
 - o 2.5 m drift distance

See poster #16 (E. Klein)





MicroBooNE Goals

- MicroBooNE will fully test LAr TPC technology at a scope and scale that will help inform the design and operation of much larger LAr TPC detectors for next-generation neutrino oscillation experiments
- Make a major contribution to the development of full reconstruction of neutrino interactions in LAr TPCs
- Investigate the source of the low energy excess seen by MiniBooNE by using the unique electron/photon discrimination power offered by LAr TPCs
- Make the first high-statistics measurements of neutrino interactions in argon

Technology

Physics



MicroBooNE Detector

- TPC active volume
 - o Length: 10.37 m
 - o Height: 2.33 m
 - Width: 2.56 m (drift length)
- o 3 wire planes
 - 2 induction planes
 - 1 collection plane
- Scintillation light detection by PMTs viewing LAr volume through wire planes



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LAr TPC Operation ArgoNeuT neutrino candiate

time





separated from vertex

Anode Wire Planes

- 3 wire planes (U,V,Y)
 - Y (3456 wires): vertical
 - U (2400 wires): +60°
 - V (2400 wires): -60°
- 3 mm wire pitch
- Fully automated wire-winding machines @ Yale & Syracuse











PMT System









- 30 PMTs mounted on a support rack outside the region of the E-field will detect scintillation light
- Ongoing tests by MIT and St. Mary's University of Minn. to study properties of wavelength shifter plates and PMTs



Front End Electronics Testing at BNL

Horizontal cold motherboard (pre-production)



- Cold electronics
 - Room temperature & cold testing of version 3 prototype CMOS ASICs & cold motherboards

• Warm interface electronics

- Intermediate amplifiers: evaluation test with pre-production boards
- Service board: under testing now
- ASIC configuration board: 1st prototype works well, new design
- Digitizing electronics
 - Receiver and ADC board: 10 pre-production version 1 pieces being assembled now







BNL/Nevis Joint Integration Test

12 Front End Modules in crate

- Nevis readout cards mated with BNL Receiver/ADC boards in Front End Modules
- Front End Electronics (ASICs, intermediate amplifiers, service boards) in test stand connected to FEMs in crate
- Successful integrated system readout test
- Ongoing tests: linearity, noise, cross talk

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Test stand with: Service board Intermediate amplifiers ASICs (in Faraday box)



Detector Assembly Area at DØ





Preparation of TPC Parts

- TPC parts cleaning/ preparation at Lab F
- ~50% of anode frame parts have arrived; assembly this summer

Various TPC parts ready to be cleaned

Lab F TPC parts prep area

TPC Assembly





LAr Test Facility Construction



- Ground-breaking January, 2012
- Steady progress through winter and spring
- Contracted beneficial occupancy: March 15, 2013
- Currently ahead of schedule





















LArTF Mock-up at Lab F





Assembly Schedule

- Machined TPC parts shipped to FNAL (Spring-Summer 2012)
- TPC frame assembly (Summer-Fall 2012)
 - Lots of activity this summer! Come watch our progress at the DØ Assembly Building.
- Cryostat delivery (Winter 2012/13)
- Cold electronics delivery/installation (Winter-Spring 2013)
- TPC installation in cryostat (Spring 2013)
- Instrumented cryostat installed in LAr Test Facility (Spring-Summer 2013)
- Ready to fill with LAr (Late 2013)



Summary

- Ongoing testing of systems
 - PMTs & wavelength shifter plates
 - Cold electronics and intermediate electronics
 - Front end module readout
- LAr Test Facility building
 - Steady progress so far; ahead of schedule
 - Mockup of building layout at Lab F
- Ramping up activities in preparation for full assembly
 Fun and exciting work this summer!

Thank you!







MicroBooNE Collaboration (16 institutions)

- Brookhaven Lab H. Chen, S. Duffin, J. Farrell, F. Lanni, Y. Li, D. Lissauer, G. Mahler, D. Makowieki, J. Mead, V. Radeka, S. Rescia, J. Sondericker, C. Thorn, K. Wu, B. Yu
- Columbia University L. Camilleri, R. Carr, G. Cheng, C. Chi, G. Karagiorgi, C. Mariani, B. Seligman, M. Shaevitz, B. Sippach, B. Willis
- Fermilab B. Baller, D. Bogert, B. Carls, H. Greenlee, C. James, H. Jostlein, M. Kirby, S. Lockwitz, B. Lundberg, S. Pordes, J. Raaf, G. Rameika, B. Rebel, R. Schmitt, D. Schmitz, J. Wu, T. Yang, S. Zeller
- Instituto Nazionale di Fisica Nucleare, Italy F. Cavanna, O. Palamara
- Kansas State University T. Bolton, D. McKee, G. Horton-Smith
- Laboratory for High Energy Physics, University of Bern, Switzerland A. Ereditato, I. Kreslo, T. Strauss, C. von Rohr, M. Weber
- Los Alamos Lab G. Garvey, J. Gonzales, B. Louis, C. Mauger, G. Mills, Z. Pavlovic, R. Van de Water, H. White
- Massachusetts Institute of Technology W. Barletta, L. Bugel, J. Conrad, C. Ignarra, B. Jones, T. Katori, A. Prakash, T. Smidt
- Michigan State University C. Bromberg, D. Edmunds
- New Mexico State University V. Papavassiliou
- Princeton University Q. He, C. Lu, K. McDonald
- St. Mary's University P. Nienaber
- Syracuse University M. Asaadi, M. Soderberg
- University of Cincinnati R. Grosso, R. Johnson, B. Littlejohn
- University of Texas at Austin S. Kopp, K. Lang, R. Mehdiyev
- Yale University C. Brasco, E. Church, B. Fleming, R. Guenette, E. Klein, A. Szelc



Event Rates

Expected event rates for 6.6 x 1	0 ²⁰ POT	3000	550	600	650	700	75
production mode	# events	Ē					
$\operatorname{CC}\operatorname{QE}\left(u_{\mu}n ightarrow\mu^{-}p ight)$	60,161	2500				14	
NC elastic $(\nu_{\mu} N \rightarrow \nu_{\mu} N)$	19,409	2000	1.1			-	
CC resonant π^+ $(\nu_{\mu} N \rightarrow \mu^- N \pi^+)$	25,149	1500		L			
CC resonant π^0 $(\nu_\mu n \to \mu^- p \pi^0)$	6,994	Ē	-	_		-	
NC resonant π^0 $(\nu_\mu N \to \nu_\mu N \pi^0)$	7,388	1000				-	
NC resonant $\pi^{\pm} (\nu_{\mu} N \rightarrow \nu_{\mu} N' \pi^{\pm})$	4,796	2000		· · · · · · · · · · · · · · · · · · ·		· · · · · · · · ·	<u>-</u>
CC DIS $(\nu_{\mu} N \rightarrow \mu^{-} X, W > 2 \text{ GeV})$	1,229	1900					
NC DIS $(\nu_{\mu} N \rightarrow \nu_{\mu} X, W > 2 \text{ GeV})$	456	1800					-
NC coherent $\pi^0 \ (\nu_\mu A \to \nu_\mu A \pi^0)$	1,694	1600				-	
CC coherent π^+ ($\nu_{\mu} A \rightarrow \mu^- A \pi^+$)	2,626	1500	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~				
NC kaon $(\nu_{\mu} N \rightarrow \nu_{\mu} K X)$	39		400	500	600	700	
CC kaon $(\nu_{\mu} N \rightarrow \mu^{-} K X)$	117	1800					
other ν_{μ}	3,678	1600		1.	-	and it is a second s	
total ν_{μ} CC	98,849	1500		<i>u</i>	-		
total ν_{μ} NC+CC	133,580	1400					
$\nu_e \text{ QE}$	326	1200					
$\nu_e CC$	657						
						0.0010	0.4



		BNB	NuMI				
-1383	Total Events	145k	60k				
	v _µ CCQE	68k	25k				
1/2	NC πº	8k	3k				
11/72	ve CCQE	0.4k	1.2k				
A IL	POT	6x10 ²⁰	8x10 ²⁰				
3.9.	Projected Event Pates for MicroPooNE in 2.2 years						

Projected Event Rates for MicroBooNE in 2-3 years.

MicroBooNE

BOONE H



Electronics System





"Warm" Electronics



Full signal feed-through assembly drawing

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Signal Feed-through

- ATLAS LAr Calorimeter style feed-through, technology 0 exists: high signal density (1920 pins)
- Pin carriers welded on flange: 100% hermetical
- Faraday box is built and mounted on feed-through
- Bias voltage feed-through to provide bias voltage filtering and reliable ground connection

Cable Assemblies

- Cold cable: Teflon FEP insulation, 100 Ω +- 10%, AWG 26 solid core sliver plated
- Warm cable assembly is commercial off-the-shelf SCSI-3 \bigcirc Ultra LVD/SE MD68M/M cable

Intermediate Amplifier

- 32 channels per board
- Differential driver to improve noise immunity \bigcirc
- Provide an appropriate gain (~12 dB) to detector signals to make it suitable for long distance (10 - 20 m)transmission

Service Board

- Provide +1.8 V control and monitoring to front end 0 ASIC, +3.3 V, -3.3 V filtering and distribution to intermediate amplifier
- Provide calibration pulse driver to front ASIC which has built in switch to turn on/off pulse injection to individual channels
- ASIC Configuration Board •

ICs and PC

Provide ASIC configuration signals interface between June 13, 2012 • 27

CMOS Analog Front End ASIC

- 16 channels per chip
- Charge amplifier, high-order filter
- Adjustable gain: 4.7, 7.8, 14, 25 mV/fC (55, 100, 18
- Adjustable filter time constant (peaking time): 0.5
- Selectable dc/ac (100 μs) coupling
- 136 registers with digital interface
- 5.5 mW/channel (input MOSFET 3.6 mW)
- Designed for long cryo-lifetime
- Circuit performance is almost identical at 300K and 77K, except noise is ~2x lower
- Calibration capacitor on ASIC changes by ~0.5% from 300K to 77K
- Prototype #1: Works, tested, fully characterized
- Prototype #2: minor fixes successful, tested, evaluated
- Prototype #3: addresses additional problems , in evaluation



Cold motherboard with 4 ASIC chips (64 channels) populated





